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Chung

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(54) **ORGANIC LIGHT-EMITTING DISPLAY
DEVICE AND METHOD OF
MANUFACTURING THE SAME**

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CPC **H01L 51/5228** (2013.01)

USPC **257/99**; 257/40

(58) **Field of Classification Search**

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See application file for complete search history.

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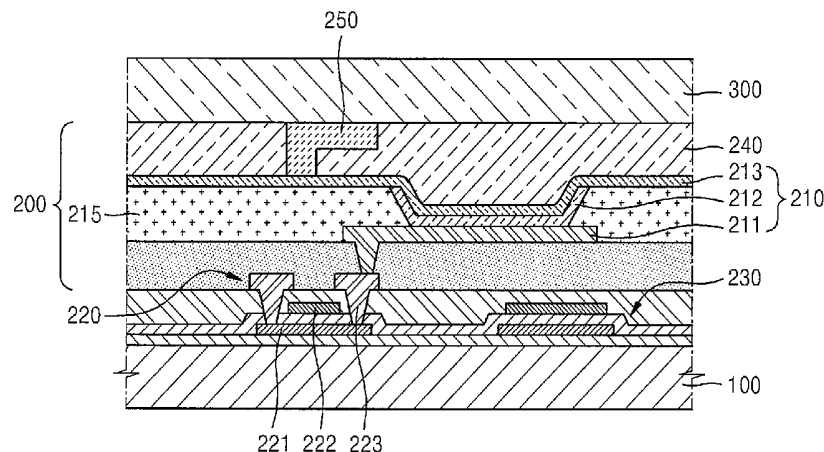
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(57) **ABSTRACT**

An organic light emitting display device including a sub-pixel
including a pixel electrode, a counter electrode, and a light
emitting layer between the pixel electrode and the counter
electrode, a planarization layer covering the counter elec-
trode, and an auxiliary electrode in the planarization layer and
coupled to the counter electrode.

4 Claims, 3 Drawing Sheets



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FIG. 1

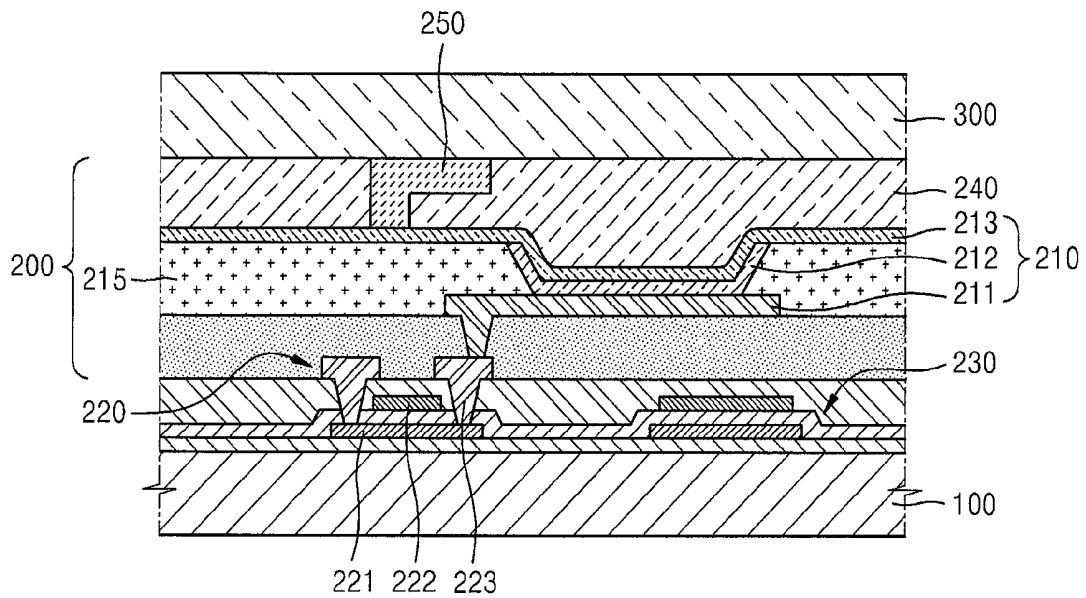


FIG. 2A

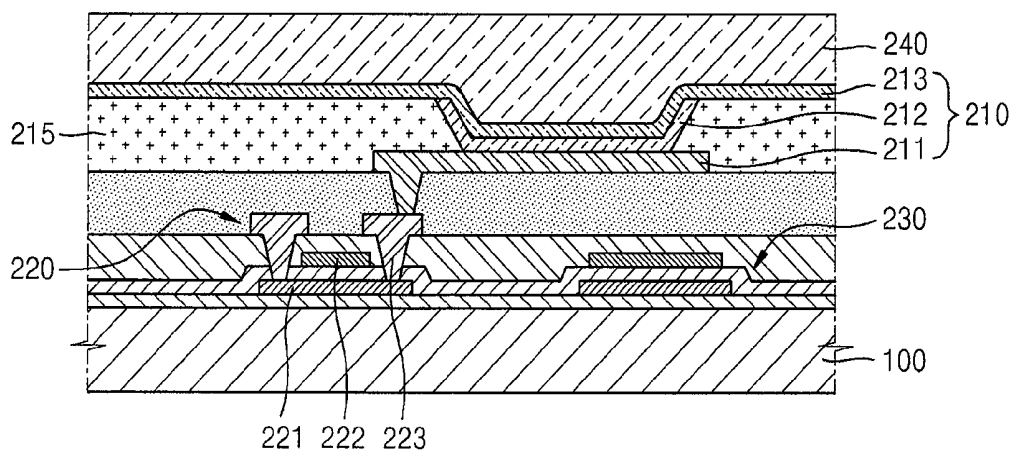


FIG. 2B

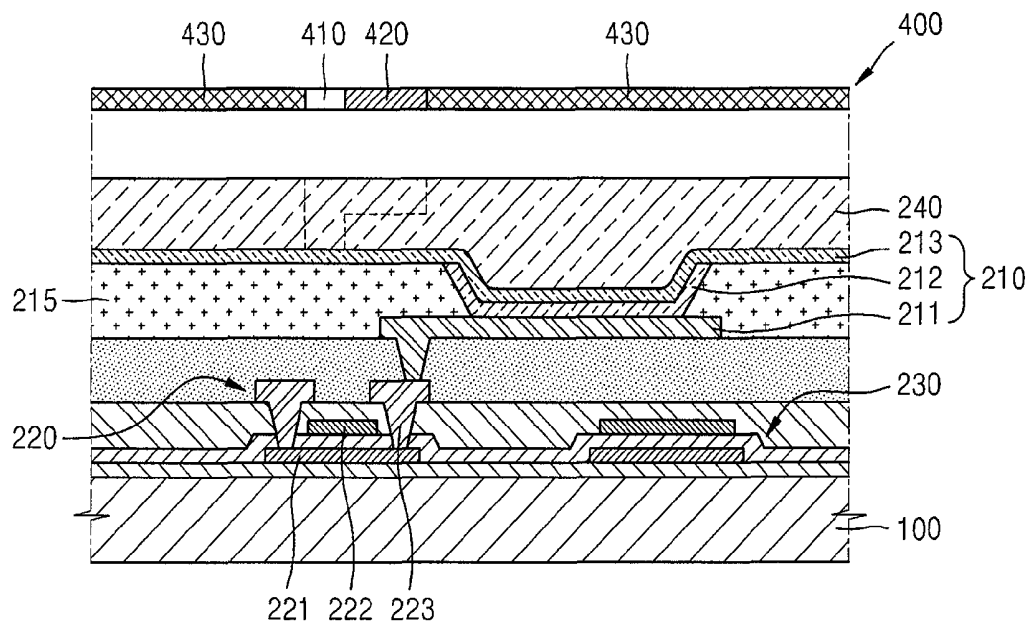


FIG. 2C

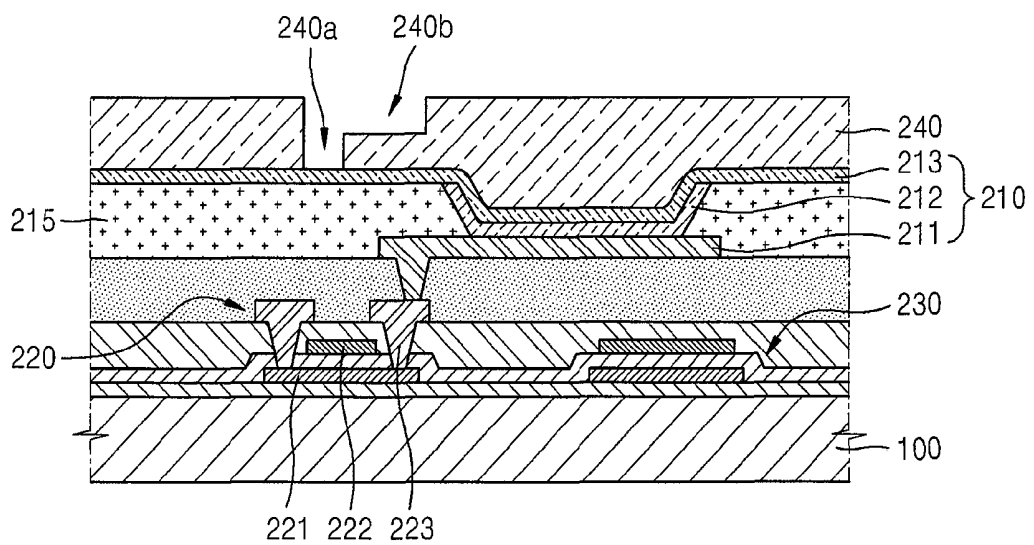


FIG. 2D

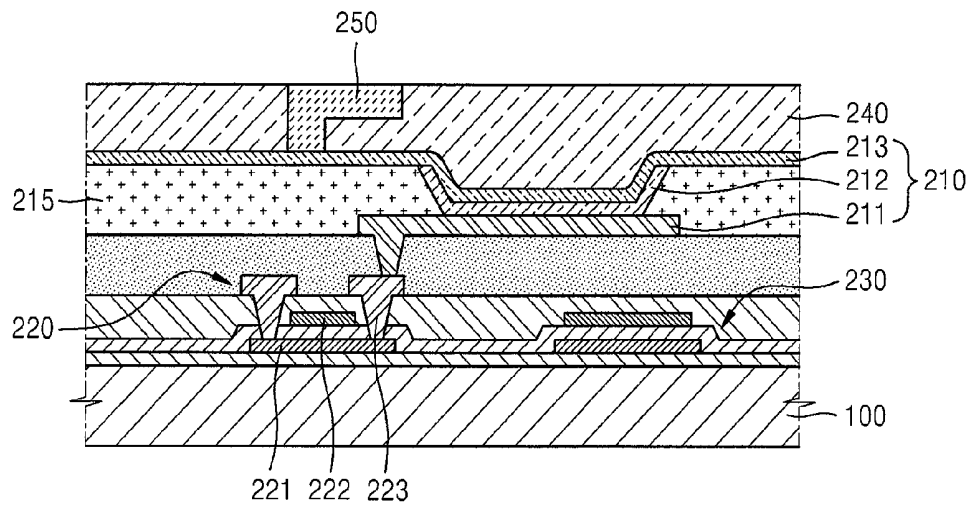
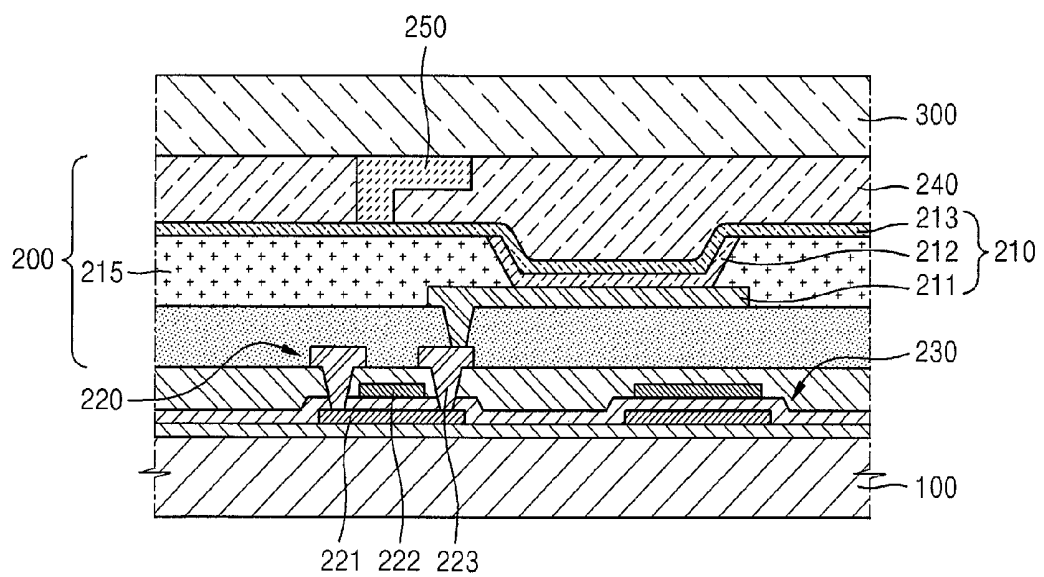


FIG. 2E



ORGANIC LIGHT-EMITTING DISPLAY DEVICE AND METHOD OF MANUFACTURING THE SAME

CROSS-REFERENCE TO RELATED PATENT APPLICATION

This application claims priority to and the benefit of Korean Patent Application No. 10-2012-0131117, filed on Nov. 19, 2012 in the Korean Intellectual Property Office, the disclosure of which is incorporated herein in its entirety by reference.

BACKGROUND

1. Field

Embodiments of the present invention relate to an organic light emitting display device and a method of manufacturing the same, and more particularly, to an organic light emitting display device having a structure for reducing or preventing a voltage drop at a counter electrode and a method of manufacturing the organic light emitting display device.

2. Description of the Related Art

Generally, an organic light emitting display device has a stacked structure in which a light emitting layer is located between a pixel electrode, which is an anode, and a counter electrode, which is a cathode. Colors are formed when holes and electrons respectively injected from anodes and cathodes are recombined at a light emitting layer that emits light.

A unit pixel of such an organic light emitting display device includes sub-pixels including a red sub-pixel, a green sub-pixel, and a blue sub-pixel, and a desired color is formed by a combination of three colors of the sub-pixels. In other words, each of the sub-pixels has a structure in which a light emitting layer emitting one color from among red, green, and blue is located between two electrodes, and a color of the unit pixel is formed by suitably combining lights of the three colors.

Furthermore, the counter electrode is generally formed as a thin metal film that covers all sub-pixels. However, since the thickness of a metal film is inversely proportional to the resistance of the metal film, a voltage drop frequently occurs due to the high resistance of the counter electrode. As a result, it may be difficult to form clear images and the reliability of the organic light emitting display having this structure is low. Therefore, it is necessary to resolve these problems.

SUMMARY

Embodiments of the present invention provide an organic light emitting display device having a structure for reducing or preventing a voltage drop at a counter electrode and a method of manufacturing the organic light emitting display device.

According to an aspect of embodiments of the present invention, there is provided an organic light emitting display device including a sub-pixel including a pixel electrode, a counter electrode, and a light emitting layer between the pixel electrode and the counter electrode, a planarization layer covering the counter electrode, and an auxiliary electrode in the planarization layer and coupled to the counter electrode.

A groove may be defined by a side of the planarization layer opposite the counter electrode, a penetration hole in the planarization layer may extend through the planarization layer toward the counter electrode from the groove, and the

auxiliary electrode may be located in the groove and the penetration hole.

The auxiliary electrode may include silver (Ag).

The planarization layer may include an organic layer.

According to another aspect of the present invention, there is provided a method of manufacturing an organic light emitting display device, the method including forming sub-pixels on a base substrate, each sub-pixel including a pixel electrode, a counter electrode, and a light emitting layer between the pixel electrode and the counter electrode, forming a planarization layer over the counter electrode, and forming an auxiliary electrode in the planarization layer and coupled to the counter electrode.

The forming of the auxiliary electrode may include forming a groove and a penetration hole in the planarization layer, and filling the groove and the penetration hole with the auxiliary electrode to couple the counter electrode to the auxiliary electrode.

Forming the groove and the penetration hole may include selectively removing one or more portions of the planarization layer using a mask including a full exposure portion, a half exposure portion, and a shading portion, the penetration hole may be in an area corresponding to the full exposure portion, and the groove may be in an area corresponding to the half exposure portion.

The forming of the auxiliary electrode may include depositing a material on a surface of the planarization layer, filling the groove and the penetration hole by radiating a laser on a portion of the material corresponding to the groove and penetration hole to melt the portion of the material, and removing a remaining portion of the material other than the portion of the material corresponding to the groove and penetration hole.

The auxiliary electrode may include silver (Ag).

The planarization layer may include an organic layer.

Therefore, according to an organic light emitting display device and a method of manufacturing the organic light emitting display device according to embodiments of the present invention, a voltage drop may be effectively reduced by coupling an auxiliary electrode to a counter electrode through a planarization layer, thereby improving the reliability of the organic light emitting display device.

BRIEF DESCRIPTION OF THE DRAWINGS

The above and other aspects of embodiments of the present invention will become more apparent by describing in detail exemplary embodiments thereof with reference to the attached drawings in which:

FIG. 1 is a cross-sectional view illustrating an organic light emitting display device according to an embodiment of the present invention; and

FIGS. 2A through 2E are cross-sectional views illustrating processes of manufacturing the organic light emitting display device of FIG. 1.

DETAILED DESCRIPTION

As used herein, the term “and/or” includes any and all combinations of one or more of the associated listed items.

Hereinafter, exemplary embodiments of the present invention will be described in detail with reference to the attached drawings.

FIG. 1 is a cross-sectional view illustrating an organic light emitting display device according to an embodiment of the present invention. As illustrated in FIG. 1, the organic light emitting display device according to the present embodiment

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includes a base substrate **100**, a display unit **200** formed thereon, and an encapsulation layer **300** covering the display unit **200**.

The display unit **200** includes a thin-film transistor (TFT) **220**, a capacitor **230**, and an organic light emitting device **210**. FIG. 1 shows a sub-pixel of the display unit **200** of the organic light emitting display device, and a plurality of such sub-pixels may be arranged in rows and columns on the base substrate **100**.

The TFT **220** includes an active layer **221** formed on the base substrate **100**, a gate electrode **222** facing the active layer **221**, and source and drain electrodes **223** that are respectively coupled to the active layer **221** and a pixel electrode **211** of the organic light emitting device **210**. Therefore, when a suitable voltage is applied to the gate electrode **222**, a current flows to the pixel electrode **211** via the active layer **221** and the source and drain electrodes **223**.

Furthermore, the organic light emitting device **210** includes the pixel electrode **211**, a light emitting layer **212** formed in a pixel defining layer **215** surrounding the pixel electrode **211**, and a counter electrode **213** formed on all of the sub-pixels of the display unit **200**. Therefore, when a voltage is applied by the TFT **220** to the pixel electrode **211** and a suitable voltage exists between the pixel electrode **211** and the counter electrode **213**, the light emitting layer **212** emits light.

In the case of a front light-emitting structure, where an image is formed towards the counter electrode **213**, the pixel electrode **211** may be formed as a reflective electrode, and the counter electrode **213** may be formed as a phototransmissive electrode.

The light emitting layer **212** may be formed by stacking a hole injection and transport layer, a light emitting layer, and/or an electron injection and transport layer.

Because the counter electrode **213** is generally formed of a thin metal film, the counter electrode **213** has high resistance, and thus, a voltage drop may occur. Therefore, to resolve this problem, a planarization layer **240** formed of an organic layer material is formed on the counter electrode **213**, and an auxiliary electrode **250** is formed in the planarization layer **240** to be electrically coupled to the counter electrode **213** in the present embodiment. In other words, the auxiliary electrode **250** is formed in the planarization layer **240** covering the counter electrode **213** such that the auxiliary electrode **250** is coupled to the counter electrode **213** through the planarization layer **240**. As a result, a voltage may also be applied to the counter electrode **213** via the auxiliary electrode **250**, and thus, a voltage drop at the counter electrode **213** may be significantly reduced.

The organic light emitting display device having the structure as described above may be manufactured as described below.

First, as shown in FIG. 2A, the display unit **200** including the TFT **220**, the organic light emitting device **210**, and the capacitor **230** is formed on the base substrate **100**. Since a process for forming the display unit **200** is well-known in the art, detailed descriptions thereof will be omitted.

The planarization layer **240**, which is formed of the organic layer material such as, for example, polyimide or hybrid silicon on glass (SOG), is formed on the counter electrode **213** of the organic light emitting device **210**.

The planarization layer **240**, or a portion thereof, is exposed by using the mask **400** as illustrated in FIG. 2B to be selectively removed from corresponding areas. That is, the mask **400** includes a full exposure portion **410**, a half exposure portion **420**, and a shading portion **430**, and an exposure

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pattern as indicated by dashed lines in FIG. 2B is formed when the planarization layer **240** is exposed using the mask **400**.

As shown in FIG. 2C, when the exposure pattern is etched, an accommodation groove **240b** and a penetration hole **240a** are formed in the planarization layer **240**. The penetration hole **240a** is formed in an area corresponding to the full exposure portion **410**, and the accommodation groove **240b** is formed in the area corresponding to the half exposure portion **420**.

Next, as illustrated in FIG. 2D, the auxiliary electrode **250** is formed in the accommodation groove **240b** and penetration hole **240a**. As a result, the auxiliary electrode **250** is coupled to the counter electrode **213** through the penetration hole **240a**, and thus, a voltage may also be applied to the counter electrode **213** through the auxiliary electrode **250**. The auxiliary electrode **250** may be formed by depositing a conductive material such as, for example, silver (Ag) and then partially melting the conductive material using a laser. That is, a material for forming the auxiliary electrode **250** may be deposited on substantially the entire surface of the planarization layer **240**, and then, a laser is radiated on a portion of the material corresponding to the accommodation groove **240b** and penetration hole **240a** to melt the portion of the material. As a result, the portion of the material for the auxiliary electrode **250** is melted, and thus, the melted material fills the accommodation groove **240b** and the penetration hole **240a**. Next, when a remaining portion of the material for the auxiliary electrode **250** is stripped, a resultant structure as shown in FIG. 2D is obtained. Although a laser is used in the present embodiment, other embodiments of the present invention may allow for the material to be melted by other methods (e.g., heat application).

Thereafter, when the encapsulation layer **300** is formed on the resultant structure, the auxiliary electrode **250** and the counter electrode **213** are stably coupled to each other through the planarization layer **240**, as illustrated in FIG. 2E.

In the structure described above, a voltage may also be applied to the counter electrode **213** via the auxiliary electrode **250**, and thus, a voltage drop at the counter electrode **213** may be reduced or prevented.

Therefore, according to the embodiments of the present invention as described above, a voltage drop may be effectively reduced by coupling the auxiliary electrode to the counter electrode through the planarization layer, thereby improving the reliability of the organic light emitting display device.

While embodiments of the present invention have been particularly shown and described with reference to exemplary embodiments thereof, it will be understood by those of ordinary skill in the art that various changes in form and details may be made therein without departing from the spirit and scope of the present invention as defined by the following claims, and their equivalents.

What is claimed is:

1. An organic light emitting display device comprising:
 - a substrate;
 - a sub-pixel comprising a pixel electrode, a counter electrode, and a light emitting layer between the pixel electrode and the counter electrode disposed on the substrate;
 - a pixel defining layer surrounding the pixel electrode;
 - a planarization layer covering the counter electrode and comprising an organic layer;
 - an encapsulation layer covering the planarization layer; and

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an auxiliary electrode, comprising a vertical portion and a horizontal portion, in the planarization layer and directly contacting the encapsulation layer, the auxiliary electrode being electrically coupled to the counter electrode and being configured to apply a voltage to the counter electrode,

wherein a first area defined by an interface between the auxiliary electrode and a first surface of the counter electrode overlaps a second area defined by an interface between a second surface of the counter electrode and the pixel defining layer, the first surface and the second surface of the counter electrode being opposing sides of the counter electrode, and

wherein the horizontal portion of the auxiliary electrode overlaps with a portion of the pixel electrode along a direction perpendicular to the first area and the second area and does not extend entirely to a first edge and a second edge of the substrate, wherein the first edge and

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the second edge extend in a direction perpendicular to the first area and the second area.

2. The organic light emitting display device of claim 1, wherein a groove is defined by a side of the planarization layer opposite the counter electrode,

wherein a penetration hole in the planarization layer extends through the planarization layer toward the counter electrode from the groove, and

wherein the auxiliary electrode is located in the groove and the penetration hole.

3. The organic light emitting display device of claim 1, wherein the auxiliary electrode comprises silver (Ag).

4. The organic light emitting display device of claim 1, wherein the auxiliary electrode has a first side and a second side facing the first side, the first and second sides of the auxiliary electrode being between an edge of a source electrode and an edge of a drain electrode of a transistor.

* * * * *

专利名称(译)	有机发光显示装置及其制造方法		
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[标]申请(专利权)人(译)	三星显示有限公司		
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发明人	CHUNG, IN-YOUNG		
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CPC分类号	H01L51/5228		
优先权	1020120131117 2012-11-19 KR		
其他公开文献	US20140138631A1		
外部链接	Espacenet USPTO		

摘要(译)

一种有机发光显示装置，包括：子像素，包括像素电极，对电极，以及位于像素电极和对电极之间的发光层；覆盖对电极的平坦化层，以及平坦化层中的辅助电极并连接到反电极。

